transistor

2SC5482

For Low Frequency Power Amplify Application Silicon NPN Epitaxial Type Micro(Frame type)

DESCRIPTION

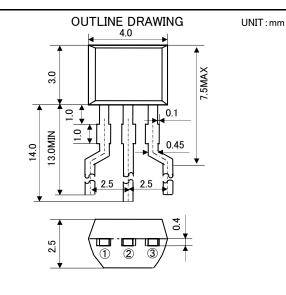
2SC5482 is a silicon NPN epitaxial designed for relay drive or power supply application.

FEATURE

- High collector current IC=1A
- Low VCE(sat) VCE(sat)=0.11V typ (@ IC=500mA,IB=25mA)
- High voltage
- VCEO= 60V
- High collector dissipation
 Pc= 600mW

APPLICATION

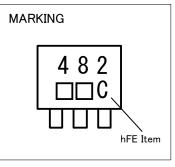
Relay drive, power supply for audio equipment, VCR, etc



TERMINAL CONNE	CTOR
1: EMITTER	FIAJ: -
2:COLLECTOR	JEDEC: -
3:BASE	OLDEO.

MAXIMUM RATINGS(Ta=25°C)

Symbol	Parameter	Ratings	Unit	
Vсво	Collector to Base voltage 60			
VEBO	Emitter to Base voltage	6	V	
VCEO	Collector to Emitter voltage	60	V	
Ісм	Peak collector current	2	А	
Ic	Collector current	1	А	
Pc	Collector dissipation	600	mW	
Tj	Junction temperature	+150	°C	
Tstg	Storage temperature	-55~+150	°C	



ELECTRICAL CHARACTERISTICS (Ta=25°C)

		Limits				
Parameter	Parameter Symbol Test conditions	Min	Тур	Max	Unit	
V(br)cbo	C to B break down voltage	I_{c} = 10 μ A , I $_{E}$ = 0mA	60	-	-	V
V(br)ebo	E to B break down voltage	$I_{E}=10 \mu$ A , $I_{C}=$ 0mA	6	-	-	V
V(BR)CEO	C to E break down voltage	I_c =2mA , RBE= ∞	60	-	-	V
Ісво	Collector cut off current	V _{CB} = 50V , I _E = 0mA	-	-	0.2	μA
IEBO	Emitter cut off current	V $_{\rm EB}$ = 4V , I $_{\rm C}$ = 0mA	-	-	0.2	μA
hFE	DC forward current gain	V $_{CE}$ =4V , I_{C} = 100mA	55	-	300	-
VCE(sat)	C to E Saturation voltage	I _C =500mA , I _B = 25mA	-	0.11	0.3	V
fT	Gain bandwidth product	V $_{CE}$ = 2V , I $_{E}$ = -10mA	-	120	-	MHz
Cob	Collector output capacitance	V _{CB} = 10V , I _E = 0mA,f=1MHz	-	14	-	pF
						P

Item	С	D	E
hFE	55 ~ 110	90~180	150~300

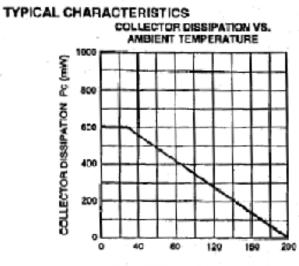
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2SC5482

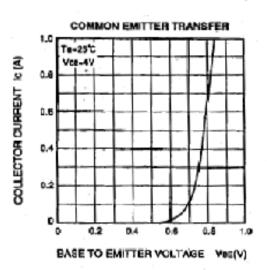
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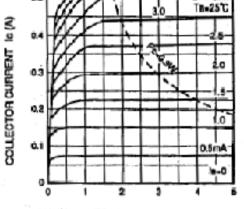
COMMON EMITTER OUTPUT

0.5



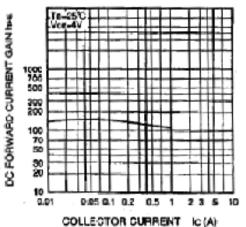
AMBIENT TEMPERATURE T. (C)

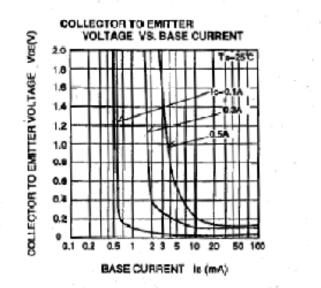


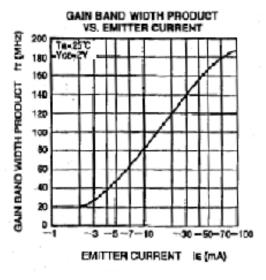


COLLECTOR TO EMITTER VOLTAGE VCE(V)

DC FORWARD CURRENT GAIN VS. COLLECTOR CURRENT





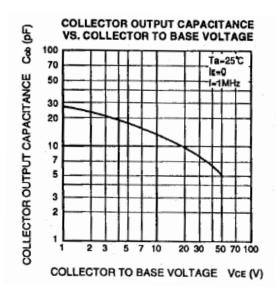


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